

# AIGaInP PN-series LED Chip

## ES-SMBRPN42B

□ Applications:

Horticulture lighting

Medical appliances

## □ Features:

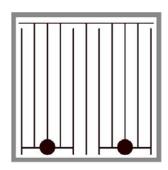
- High radiant flux
- Thin film structure
- Vertical electrode
- High driving current

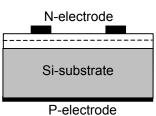
## Mechanical Specification:

(1) Dimension

Chip size : 42 mil x 42 mil (1066±25µm x 1066±25µm) Thickness : 8.8 mil (225 ± 25 µm) N bonding pad : 4.3 mil (110 ± 10 µm)

(2) MetallizationTopside N electrode : Au alloy (x2)Backside P electrode : Au alloy





### □ Electro-optical Characteristics at 25 °C:

Parameter	Symbol		Condition	Min.	Тур.	Max.	Unit
Forward voltage	V <sub>f1</sub>		I <sub>f</sub> =10uA	1.3			V
	V <sub>f2</sub>		I <sub>f</sub> =350mA		2.2	3.0	V
Reverse current	l <sub>r</sub>		V <sub>r</sub> =10V			5.0	μA
Peak wavelength <sup>(1)</sup>	λρ		I <sub>f</sub> =350mA	650	660	670	nm
Spectral half-width	Δλ		I <sub>f</sub> =350mA		20		nm
Radiant flux <sup>(2)(3)</sup>	Po	H8	I <sub>f</sub> =350mA	145			mW
		H9		175			

Note:

(1) Basically, the wavelength span is 20nm; however, customers' special requirements are also welcome.

(2) Customers' special requirements are also welcome.

(3) Radiant flux is measured by EPISTAR's equipment on bare chips.



## □ Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC current	lf	Ta=25°C	≤ <b>5</b> 00	mA
Reverse voltage	Vr	Ta=25°C	≤ <b>10</b>	V
Junction temperature	Tj	Tj		°C
		chip	-40 ~ +85	°C
Storage temperature	T <sub>stg</sub>	chip-on-tape/storage	0 ~ 40	°C
		chip-on-tape/transportation	-20 ~ +65	°C
Temperature during packaging			280(<10sec)	°C

Note:

Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MCPCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

### □ Characteristic Curves:

Fig.1- Relative Radiant Flux vs. Forward Current

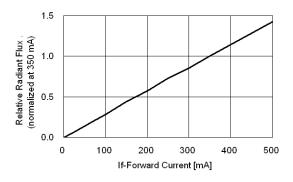
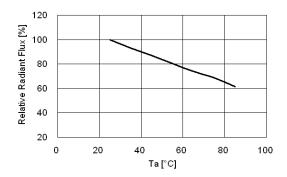


Fig.3- Relative Radiant Flux (@350mA) vs. Ambient Temperature





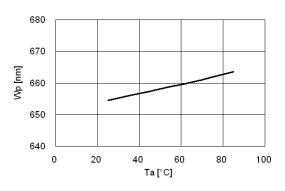


Fig.2- Forward Current vs. Forward Voltage

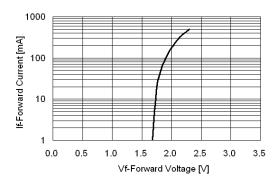


Fig.4-Forward Voltage (@350mA) vs. Ambient Temperature

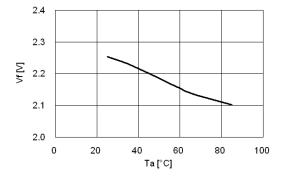
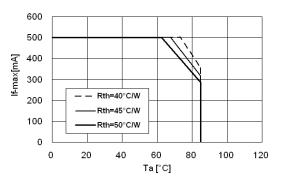


Fig.6 Maximum Driving Forward DC Current vs. Ambient Temperature (Derating based on Tj max. = 115°C)



COPYRIGHT ©2010 Epistar Corporation. All Rights Reserved.